

### **INCHANGE SEMICONDUCTOR**

## isc N-Channel MOSFET Transistor

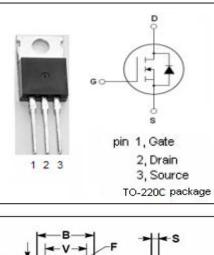
## **IXTP76N075T**

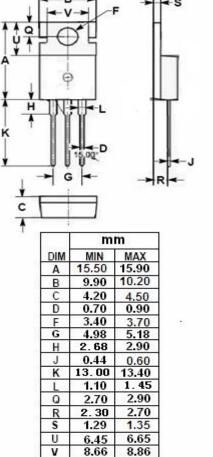
#### FEATURES · Static drain-source on-resistance: $R_{DS}(on) \le 12m\Omega @V_{GS}=10V$ · Fully characterized avalanche voltage and current 100% avalanche tested Minimum Lot-to-Lot variations for robust device performance and reliable operation 123 APPLICATION DC/DC Converters · High Current Switching Applications ABSOLUTE MAXIMUM RATINGS(Ta=25°C) SYMBOL PARAMETER VALUE UNIT VDSS **Drain-Source Voltage** 75 V V V<sub>GS</sub> Gate-Source Voltage $\pm 20$ Drain Current-Continuous 76 $I_D$ А с Drain Current-Single Pulsed 210 А **I**DM DIM $P_{D}$ Total Dissipation @Tc=25°C W 176 А В **Operating Junction Temperature** -55~175 °C С Τį D F Storage Temperature -55~175 °C G Tstg Н J K

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th(j-c)</sub>	Junction-to-case thermal resistance	0.85	°C/W

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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID = 250 μ A	75		V
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID = 50 μ A	2.0	4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 25A		12	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V		±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V		1	- μ <b>Α</b>
		V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V;T <sub>J</sub> = 150°C		250	
$V_{\text{SD}}$	Diode forward voltage	I <sub>F</sub> = 25A; V <sub>GS</sub> = 0V		1.1	V

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